



#### DMN95H8D5HCT

N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

BV <sub>DSS</sub> (@ T <sub>J</sub> Max)	R <sub>DS(ON)</sub>	Ι <sub>D</sub> T <sub>C</sub> = +25°C
1000V	$7\Omega@V_{GS} = 10V$	2.5A

#### Description

This new generation MOSFET features low on-resistance and fast switching, making it ideal for high efficiency power management applications.

### Applications

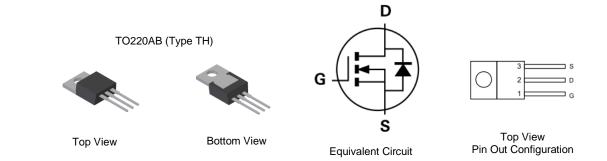
- Motor Control
- Backlighting
- **DC-DC Converters**
- **Power Management Functions**

#### Features

- Low Input Capacitance
- High BV<sub>DSS</sub> Rating for Power Application
- Low Input/Output Leakage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

#### **Mechanical Data**

- Case: TO220AB (Type TH) •
- Case Material: Molded Plastic, "Green" Molding Compound, UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram Below
- Weight: 1.85 grams (Approximate)



#### Ordering Information (Note 4)

	Part Number	Case	Packaging		
DMN95H8D5HCT		TO220AB (Type TH)	50 pieces/tube		
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.					

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2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**



) : : = Manufacturer's Marking 95H8D5H = Product Type Marking Code YYWW = Date Code Marking YY or <u>YY</u> = Last Two Digits of Year (ex: 16 = 2016) WW or WW = Week Code (01 to 53)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V <sub>DSS</sub>	950	V
Gate-Source Voltage			V <sub>GSS</sub>	±30	V
Continuous Drain Current $V_{GS}$ = 10V	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	ID	2.5 1.5	А
Maximum Body Diode Forward Current (Note 5)	Is	3	А		
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			IDM	3	A
Avalanche Current, L = 60mH (Note 7)			I <sub>AS</sub>	1.8	A
Avalanche Energy, L = 60mH (Note 7)			E <sub>AS</sub>	97	mJ
Peak Diode Recovery dv/dt			dv/dt	3.3	V/ns

## **Thermal Characteristics**

Characteristic		Symbol	Value	Units	
Tatal Rower Dissipation	$T_{\rm C} = +25^{\circ}{\rm C}$	D	125	W	
Total Power Dissipation	$T_{\rm C} = +100^{\circ}{\rm C}$	PD	50	٧V	
Thermal Resistance, Junction to Ambient (Note 6)	$R_{ ext{ heta}JA}$	50	°C/W		
Thermal Resistance, Junction to Case	R <sub>θ</sub> JC	1			
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	950	_		V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	$V_{DS} = 950V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	—	_	100	nA	$V_{GS} = \pm 30V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)			•		•		
Gate Threshold Voltage	V <sub>GS(TH)</sub>	3.0	4.0	5.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		5.5	7	Ω	$V_{GS} = 10V, I_D = 1A$	
Diode Forward Voltage	V <sub>SD</sub>	_	0.84	1.2	V	$V_{GS} = 0V, I_S = 2A$	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	Ciss		470			$V_{DS} = 25V, f = 1.0MHz,$ $V_{GS} = 0$	
Output Capacitance	Coss	—	45	_	pF		
Reverse Transfer Capacitance	Crss		0.6	_			
Gate Resistance	R <sub>G</sub>	_	1.2	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge	Qg	_	7.9				
Gate-Source Charge	Q <sub>gs</sub>	_	2.5	_	nC	$V_{DD} = 720V, I_D = 2A,$ $V_{GS} = 10V$	
Gate-Drain Charge	Q <sub>gd</sub>	_	2.9			VGS = 10V	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	16	_			
Turn-On Rise Time	t <sub>R</sub>	_	21			$\label{eq:VDD} \begin{split} V_{DD} &= 450V, \ R_G = 25\Omega, \ I_D = 2A, \\ V_{GS} &= 10V \end{split}$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>		17.6		ns		
Turn-Off Fall Time	tF		17		]		
Body Diode Reverse Recovery Time	t <sub>RR</sub>	_	375	_	ns	dl/dt = 100A/µs, V <sub>DS</sub> = 100V,	
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>		2.9		μC	$I_F = 2A$	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

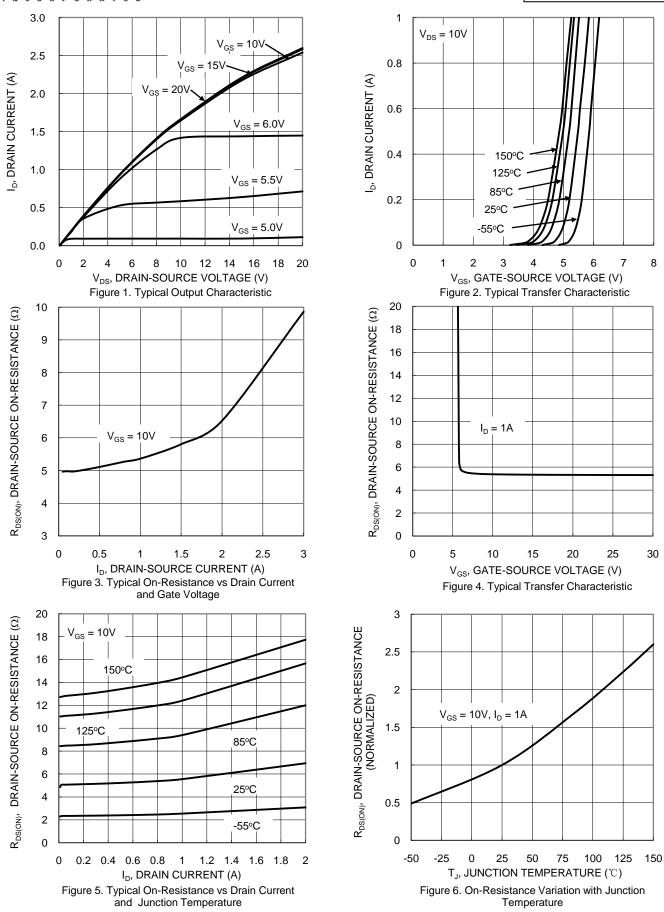
6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

7. Guaranteed by design. Not subject to production testing.

8. Short duration pulse test used to minimize self-heating effect.

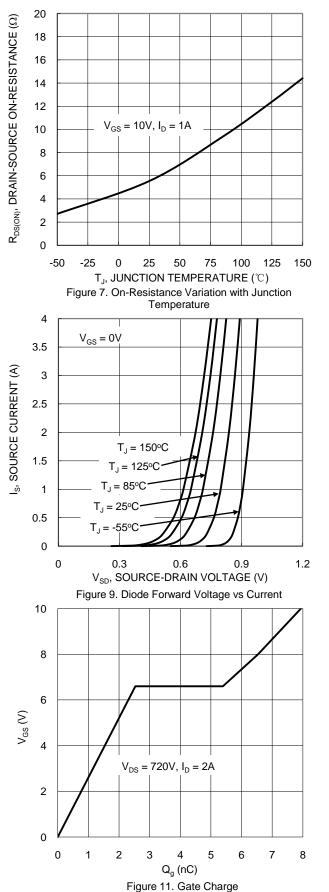


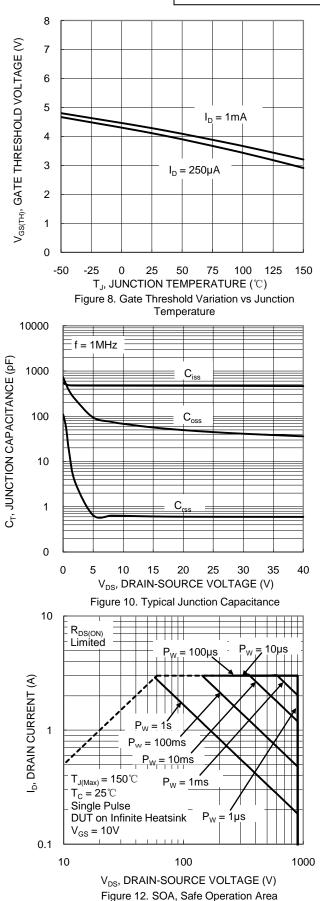




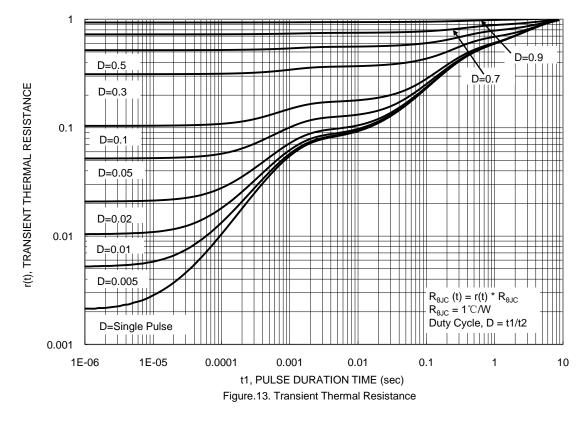












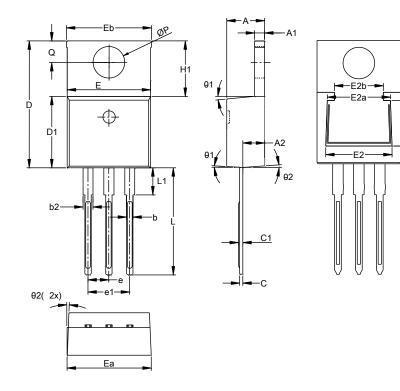


## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### TO220AB (Type TH)

D2a D2



TO220AB (Type TH)						
Dim	Min Max Ty					
Α	4.27	4.87	4.57			
A1	1.12	1.42	1.27			
A2	2.39	2.99	2.69			
b	0.70	1.01	0.81			
b2	1.17	1.50	1.27			
c	0.30	0.53	0.38			
c1	0.38	0.72	0.56			
D	14.60	15.40	15.00			
D1	8.40	8.40 9.00 8.7				
D2	5.33	6.33				
D2a	4.54 5.84 5.54					
е	2.54 BSC					
e1		5.08 BSC				
ш	9.88	10.50	10.16			
Ea	9.90	10.45	10.10			
Eb	9.90	10.65	10.25			
E2	7.06	8.36	8.06			
E2a	6.67	7.97	7.67			
E2b	4.94	6.24	5.94			
H1	5.70 6.65 6.30					
L	13.00	00 13.80 13.4				
L1	-	4.10 3.75				
Q	2.50	2.99	2.74			
ØP	3.70	3.99 3.84				
θ1	4°	10°	7°			
θ2	0°	6°	3°			
All Dimensions in mm						



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